# OSRAM SPL S4L90A\_3 A01 **Datasheet**





### **SMT Laser**

## SPL S4L90A\_3 A01

4 Channel SMT Laser in QFN package









### **Applications**

- 3D Sensing
- CCTV Surveillance
- Industrial Automation (Machine Controls, Light Barriers, Vision Controls)
- LIDAR, Pre-Crash, ACC
- Pedestrian Protection / Lane Departure Warning

#### **Features**

- Qualifications: AEC-Q102 Qualified
- Laser wavelength 905 nm
- 4 channel pulsed laser module
- Suited for short laser pulses from 1 to 100 ns
- SMT device



### **Ordering Information**

Type Peak output power Ordering Code

 $I_F = 40 \text{ A}; t_p = 100 \text{ ns}; D = 0.01 \text{ %}; T_S = 25 \text{ °C}$ 

SPL S4L90A\_3 A01 120 W Q65112A6167



### **Maximum Ratings**

T<sub>s</sub> = 25 °C

| Parameter                                           | Symbol         | Values |        |
|-----------------------------------------------------|----------------|--------|--------|
| Operating temperature                               | $T_{op}$       | min.   | -40 °C |
|                                                     |                | max.   | 105 °C |
| Storage temperature                                 | $T_{stg}$      | min.   | -40 °C |
|                                                     | 0.9            | max.   | 125 °C |
| Junction temperature                                | $T_{j}$        | max.   | 125 °C |
| Forward current                                     | I <sub>F</sub> | max.   | 40 A   |
| Pulse width (FWHM)                                  | t <sub>P</sub> | max.   | 100 ns |
| Duty cycle T <sub>s</sub> = 105 °C; all channels ON | dc             | max.   | 0.05 % |
| Duty cycle                                          | dc             | max.   | 0.2 %  |
| $T_s$ = 105 °C; one channel ON                      |                |        |        |
| Reverse voltage 1)                                  | $V_{R}$        | max.   | 45 V   |



### **Characteristics**

 $I_{_{\rm F}}$  = 40 A;  $t_{_{\rm D}}$  = 100 ns; D = 0.01 %;  $T_{_{
m S}}$  = 25 °C

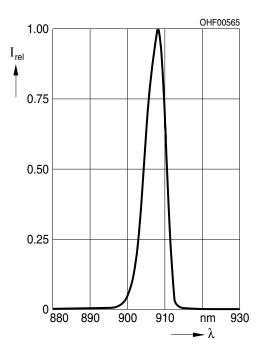
| Parameter                                           | Symbol                        |      | Values   |
|-----------------------------------------------------|-------------------------------|------|----------|
| Number of channels                                  | N                             | typ. | 4        |
| Pitch                                               | р                             | typ. | 312 µm   |
| Operating voltage                                   | V <sub>op</sub>               | typ. | 11 V     |
| Peak wavelength                                     | $\lambda_{\sf peak}$          | typ. | 908 nm   |
| Centroid wavelength 2)                              | $\lambda_{centroid}$          | min. | 895 nm   |
|                                                     |                               | typ. | 905 nm   |
|                                                     |                               | max. | 915 nm   |
| Spectral bandwidth (FWHM)                           | $\Delta \lambda$              | min. | 3 nm     |
|                                                     |                               | typ. | 7 nm     |
|                                                     |                               | max. | 12 nm    |
| Peak output power 3)                                | $P_{opt}$                     | min. | 105 W    |
|                                                     | ·                             | typ. | 125 W    |
|                                                     |                               | max. | 145 W    |
| Beam divergence (FWHM) parallel to pn-junction      | $\Theta_{_{\parallel}}$       | min. | 3 °      |
|                                                     |                               | typ. | 10 °     |
|                                                     |                               | max. | 13 °     |
| Beam divergence (FWHM) perpendicular to pn-junction | $\Theta_{\perp}$              | min. | 20 °     |
|                                                     |                               | typ. | 25 °     |
|                                                     |                               | max. | 30 °     |
| Beam divergence (1/e²) parallel to pn-junction      | $\Theta_{_{\parallel}}$       | min. | 10 °     |
|                                                     |                               | typ. | 13 °     |
|                                                     |                               | max. | 16 °     |
| Beam divergence (1/e²) perpendicular to pn-junction | $\Theta_{\perp}$              | min. | 35 °     |
|                                                     |                               | typ. | 40 °     |
|                                                     |                               | max. | 50 °     |
| Threshold current                                   | I <sub>th</sub>               | typ. | 0.6 A    |
| Laser aperture (FWHM) parallel to pn-junction       | $W_{\parallel}$               | typ. | 220 µm   |
| Laser aperture (FWHM) perpendicular to pn-junction  | $W_{\scriptscriptstyle\perp}$ | typ. | 10 µm    |
| Thermal resistance junction solder point real 4)    | $R_{thJSreal}$                | typ. | 17 K / W |
| all channels ON                                     |                               | max. | 20 K / W |

Unless otherwise specified, all values are valid for one emitter operated seperately Note:



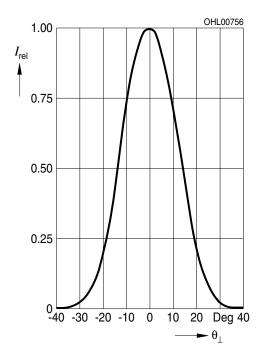
### Relative Spectral Emission 5), 6)

$$I_{\rm e,rel}$$
 = f ( $\Lambda$ );  $I_{\rm F}$  = 40A;  $P_{\rm opt}$  = 125W;  $t_{\rm p}$  = 100ns; D = 0.01%



### Far-Field Distribution Perpendicular to pn-Junction 5), 6)

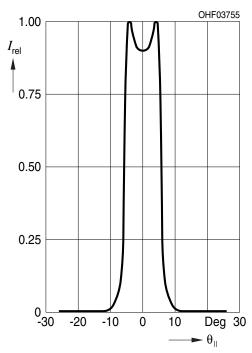
 $I_{rel}$  = f ( $\Theta$  $_{\perp}$ );  $P_{opt}$  = 125W;  $t_{p}$  = 100ns; D = 0.01%





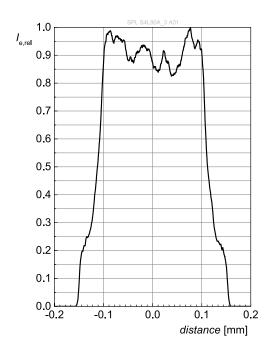
### Far-Field Distribution Parallel to pn-Junction 5), 6)

 $I_{rel} = f(\Theta II); P_{opt} = 125W; t_p = 100ns; D = 0.01\%$ 



### Near-Field Distribution Parallel to pn-Junction 5), 6)

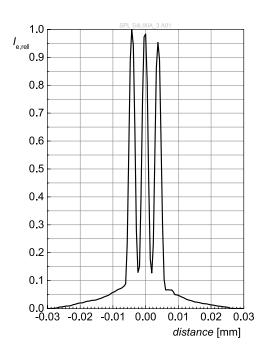
 $I_{rel} = f(\Theta II); P_{opt} = 125W; t_p = 100ns; D = 0.01\%$ 





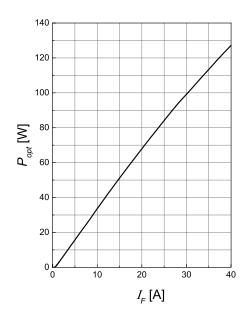
### Near-Field Distribution Perpendicular to pn-Junction 5), 6)

 $I_{rel} = f(\Theta_{\perp}); P_{opt} = 125W; t_p = 100ns; D = 0.01\%$ 



### Optical Output Power 5), 6)

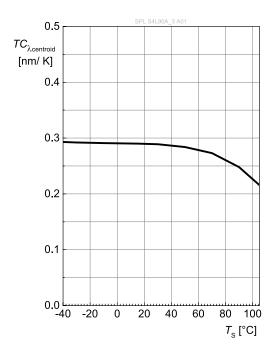
 $P_{opt} = f(I_F)$ 





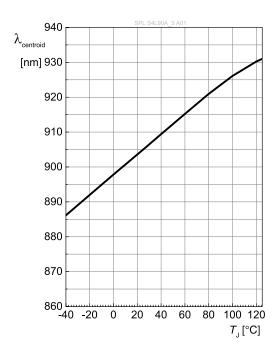
#### Centroid Wavelength 5)

$$\lambda_{centroid}$$
 = f(T<sub>S</sub>); I<sub>F</sub> = 40A; t<sub>p</sub> = 100ns; D = 0.01%



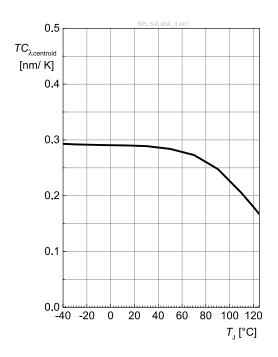
### Centroid Wavelength 5)

$$\rm \Lambda_{centroid}^{} = f (T_{_J}^{}); \, I_{_F}^{} = 40A; \, t_{_D}^{} = 100ns; \, D = 0.01\%$$



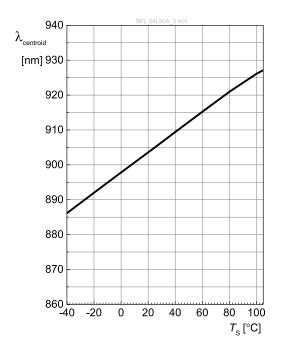
### Centroid Wavelength 5)

$$\rm \Lambda_{centroid}$$
 = f (T<sub>J</sub>); I<sub>F</sub> = 40A; t<sub>p</sub> = 100ns; D = 0.01%



### Centroid Wavelength 5)

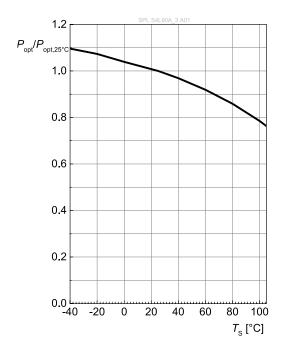
$$\lambda_{\text{centroid}}$$
 = f(T<sub>S</sub>); I<sub>F</sub> = 40A; t<sub>p</sub> = 100ns; D = 0.01%



### **OSRAM**

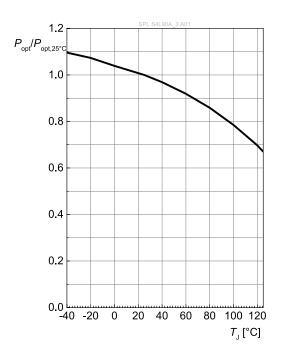
#### **Peak Output Power**

 $P_{opt} = f(T_S); I_F = 40A; t_D = 100ns; D = 0.01\%$ 



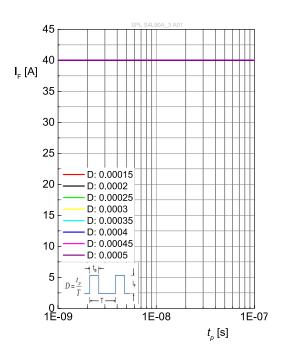
#### **Peak Output Power**

 $P_{opt} = f(T_J); I_F = 40A; t_o = 100ns; D = 0.01\%$ 



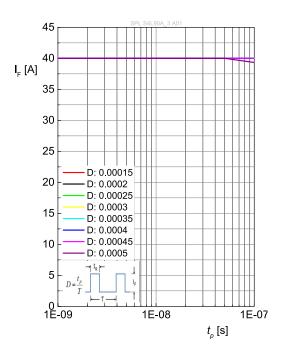
### Permissible Pulse Handling Capability

 $I_F = f(t_p)$ ; D = parameter;  $P_{opt, typ}$ ;  $R_{thjs, typ}$ ;  $T_S = 85$ °C



### Permissible Pulse Handling Capability

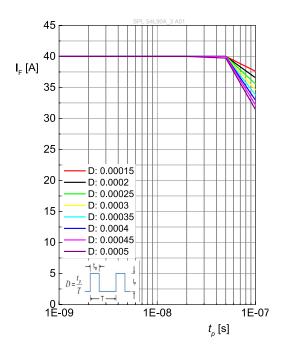
 $I_F = f(t_p)$ ; D = parameter;  $P_{opt, min}$ ;  $R_{thjs, max}$ ;  $T_S = 85$ °C





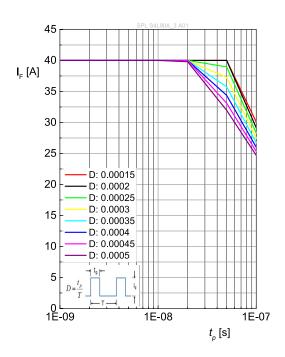
### Permissible Pulse Handling Capability

### $I_{_{\rm F}}$ = f ( $t_{_{\rm p}}$ ); D = parameter; $P_{_{{\rm opt,\,typ}}}$ ; $R_{_{{\rm thjs,\,typ}}}$ ; $T_{_{\rm S}}$ = 105°C



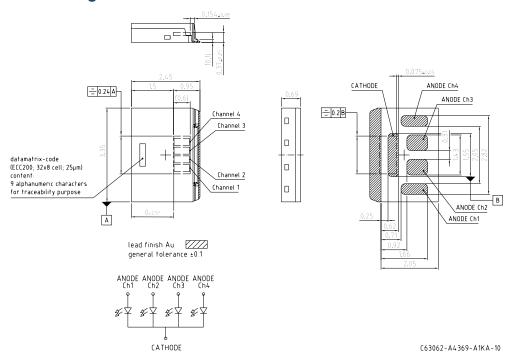
#### Permissible Pulse Handling Capability

$$I_F = f(t_p); D = parameter; P_{opt, min}; R_{thjs, max}; T_S = 105^{\circ}C$$





### **Dimensional Drawing** 7)

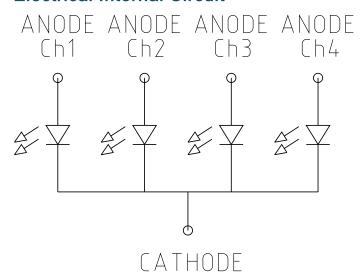


### **Further Information:**

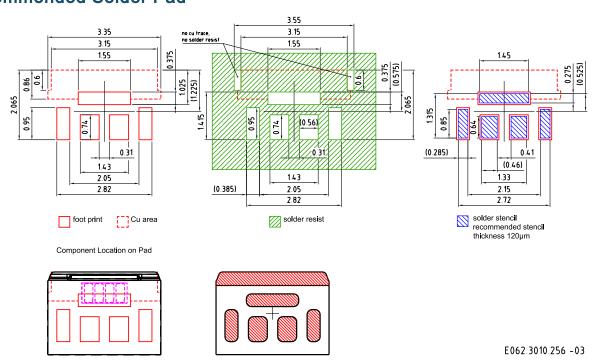
**Approximate Weight:** 15.0 mg



#### **Electrical Internal Circuit**



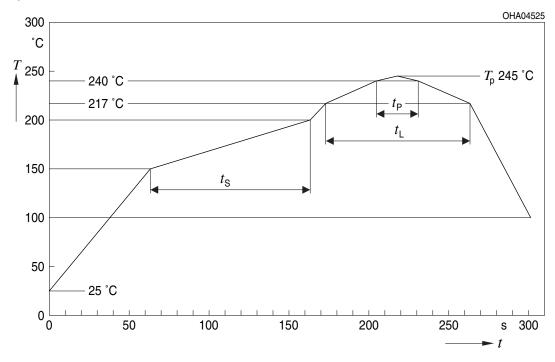
#### Recommended Solder Pad 7)





### **Reflow Soldering Profile**

Product complies to MSL Level 3 acc. to JEDEC J-STD-020E



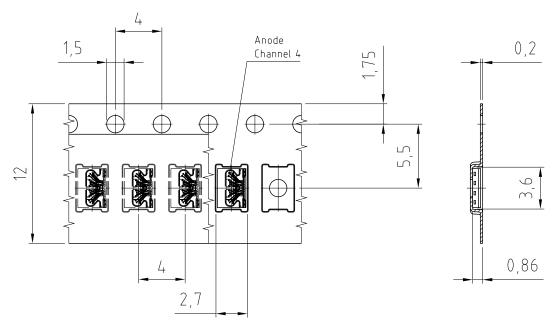
| Profile Feature                                                         | Symbol                         | ymbol Pb-Free (SnAgCu) Assembly |                |         | Unit |
|-------------------------------------------------------------------------|--------------------------------|---------------------------------|----------------|---------|------|
|                                                                         |                                | Minimum                         | Recommendation | Maximum |      |
| Ramp-up rate to preheat*)                                               | '                              |                                 | 2              | 3       | K/s  |
| 25 °C to 150 °C                                                         |                                |                                 |                |         |      |
| Time t <sub>s</sub>                                                     | t <sub>s</sub>                 | 60                              | 100            | 120     | S    |
| $T_{Smin}$ to $T_{Smax}$                                                |                                |                                 |                |         |      |
| Ramp-up rate to peak*)                                                  |                                |                                 | 2              | 3       | K/s  |
| $T_{Smax}$ to $T_{P}$                                                   |                                |                                 |                |         |      |
| Liquidus temperature                                                    | $T_{L}$                        |                                 | 217            |         | °C   |
| Time above liquidus temperature                                         | $t_{\scriptscriptstyle \perp}$ |                                 | 80             | 100     | S    |
| Peak temperature                                                        | T <sub>P</sub>                 |                                 | 245            | 260     | °C   |
| Time within 5 °C of the specified peak temperature T <sub>p</sub> - 5 K | t <sub>P</sub>                 | 10                              | 20             | 30      | S    |
| Ramp-down rate* T <sub>P</sub> to 100 °C                                |                                |                                 | 3              | 6       | K/s  |
| Time<br>25 °C to T <sub>P</sub>                                         |                                |                                 |                | 480     | S    |

All temperatures refer to the center of the package, measured on the top of the component

<sup>\*</sup> slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



### Taping 7)



C63062-A4369-B10-03



### Tape and Reel 8)



### **Reel Dimensions**

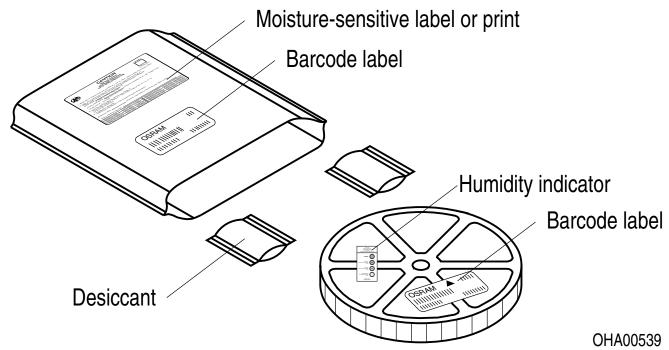
| Α      | W                   | $N_{\min}$ | $W_1$       | $W_{2  \text{max}}$ | Pieces per PU |
|--------|---------------------|------------|-------------|---------------------|---------------|
| 180 mm | 12 + 0.3 / - 0.1 mm | 60 mm      | 12.4 + 2 mm | 18.4 mm             | 500           |



### **Barcode-Product-Label (BPL)**



### Dry Packing Process and Materials 7)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



#### **Notes**

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

#### Tape and Reel:

Packing unit can vary 2 % from the stated value.

For further application related information please visit www.osram-os.com/appnotes



#### Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



#### **Glossary**

- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any reverse bias shall be avoided.
- 2) Wavelength: The wavelengths are measured with a tolerance of ±1 nm.
- 3) **Brightness:** The brightness values are measured with a tolerance of ±11%.
- Thermal resistance: junction soldering point, of the device only, mounted on an ideal heatsink (e.g. metal block)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 6) **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



#### **Revision History**

| Novicion initially |            |                 |  |  |
|--------------------|------------|-----------------|--|--|
| Version            | Date       | Change          |  |  |
| 1.0                | 2022-02-21 | Initial Version |  |  |
|                    |            | New Layout      |  |  |



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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